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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO	
10/052,234	01/16/2002	Duc Chau	40013.003	9589	
27966	7590 09/23/2004		EXAMINER		
KENNETH E. HORTON			GARCIA, JOANNIE A		
KIRTON & MCCONKLE 60 EAST SOUTH TEMPLE			ART UNIT	PAPER NUMBER	
SUITE 1800			2823		
SALTLAKE CITY, UT 84111			DATE MAILED: 09/23/2004	DATE MAILED: 09/23/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	<b>74</b>			
	10/052,234	CHAU ET AL.				
Office Action Summary	Examiner	Art Unit				
	Joannie A García	2823				
The MAILING DATE of this communication Period for Reply	n appears on the cover sheet wit	h the correspondence addr	ess			
A SHORTENED STATUTORY PERIOD FOR R THE MAILING DATE OF THIS COMMUNICATI  - Extensions of time may be available under the provisions of 37 C after SIX (6) MONTHS from the mailing date of this communicatic  - If the period for reply specified above is less than thirty (30) days, - If NO period for reply is specified above, the maximum statutory p  - Failure to reply within the set or extended period for reply will, by Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b).	ON. FR 1.136(a). In no event, however, may a re n. a reply within the statutory minimum of thirty eriod will apply and will expire SIX (6) MONT statute, cause the application to become ABA	ply be timely filed (30) days will be considered timely. HS from the mailing date of this commandoned (35 U.S.C. § 133).	munication.			
Status						
1) Responsive to communication(s) filed on	,					
	This action is non-final.					
•	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
4) ⊠ Claim(s) <u>1-31</u> is/are pending in the application 4a) Of the above claim(s) <u>18-20 and 25-37</u> 5) ⊠ Claim(s) <u>3,4,7-11,22 and 23</u> is/are allowed 6) ⊠ Claim(s) <u>1,2,5,6,12,13,16,17,21 and 24</u> is 7) ⊠ Claim(s) <u>14 and 15</u> is/are objected to. 8) □ Claim(s) are subject to restriction and 24	is/are withdrawn from considerd. d. /are rejected.	ation.				
Application Papers						
9)☐ The specification is objected to by the Exa	miner.					
10) The drawing(s) filed on is/are: a)	accepted or b) objected to b	y the Examiner.				
Applicant may not request that any objection to	= ' '					
Replacement drawing sheet(s) including the or 11) The oath or declaration is objected to by the	,	-				
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for fo a) All b) Some * c) None of:  1. Certified copies of the priority documents. Certified copies of the priority documents. Copies of the certified copies of the application from the International B * See the attached detailed Office action for the second secon	ments have been received. ments have been received in Ap priority documents have been o ureau (PCT Rule 17.2(a)).	oplication No received in this National St	tage			
Attachment(s)	A> □   Indon :: C:	www.n.v (PTO 442)				
<ol> <li>Notice of References Cited (PTO-892)</li> <li>Notice of Draftsperson's Patent Drawing Review (PTO-94)</li> </ol>		ummary (PTO-413) )/Mail Date	•			
3) Information Disclosure Statement(s) (PTO-1449 or PTO/S Paper No(s)/Mail Date		formal Patent Application (PTO-1 $\_$ ·	152)			

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Claims 12-17, and 24, are objected to because of the following informalities:

Claims 12 and 24, recite the limitation "portion of the substrate not containing the nitride-containing layer" in lines 4-5, and 5-6, respectively. There is insufficient antecedent basis for this limitation in the claim.

Claim 13 recites the limitation "distance" in line 1. There is insufficient antecedent basis for this limitation in the claim.

Appropriate correction is required.

In claim 14, line 1, "polysilicon" should be preceded by --doped--.

Claim 15 recites the limitation "polysilicon layer" in line 2. There is insufficient antecedent basis for this limitation in the claim.

Claim 16 recites the limitation "polysilicon layer" in lines 2-3. There is insufficient antecedent basis for this limitation in the claim.

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1, 2, 5, 6, 12, 16, 17, 21, and 24, are rejected under 35 U.S.C. 102(e) as being anticipated by Yamada et al (U.S. Patent 6,770,535).

Yamada et al discloses providing a semiconductor substrate 1 with an upper surface (Figure 1), providing a nitride-containing layer 5 on a portion of the substrate upper surface

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(Figure 3), providing a trench 7a/7b in the substrate in a portion of the substrate not containing the nitride-containing layer thereon (Figures 4-5), providing a gate oxide layer 8a on a bottom and sidewall of the trench (Figure 9), providing a conductive layer 9a on a bottom and sidewall of the gate oxide layer (Figure 12), the conductive layer having an upper surface below the upper surface of the substrate (Figure 14), providing a self-aligned isolation cap 10/12a within the trench by selectively depositing a non-organic dielectric material, such as silicon oxide, on the upper surface of the conductive layer (Figures 19, and 21, and Column 17, lines 7-15), and by depositing a combination of dielectric materials with different etching rats such as silicon nitride and silicon oxide (Figures 15, 16, 19, and 21, Column 15, lines 57-63, and Column 17, lines 7-15), and removing the nitride-containing layer (Figures 19 and 21).

Yamada et al discloses providing a semiconductor substrate 1 with an upper surface (Figure 36), providing source and channel regions 15a in the substrate (Figure 38), providing a nitride-containing layer 5 on a portion of the substrate upper surface (Figure 36), providing a trench 7 in the substrate in a portion of the substrate not containing the nitride-containing layer thereon (Figures 36), providing a gate oxide layer 8a on a bottom and sidewall of the trench (Figure 37), providing a conductive layer 9a on a bottom and sidewall of the gate oxide layer, wherein the conductive layer comprises metal (Figure 37, and Column 23, lines 62-65), the conductive layer having an upper surface below the upper surface of the substrate (Figure 38), providing a self-aligned isolation cap 41/42a within the trench comprising a non-organic dielectric material, such as silicon oxide (Figure 42, and Column 24, lines 12-37), and removing the nitride-containing layer (Figure 38).

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Claim 13 is rejected under 35 U.S.C. 103(a) as being unpatentable over Yamada et al as applied to claims 1, 2, 5, 6, 12, 16, 17, 21, and 24 above, and further in view of the following comments.

With respect to claim 13, it would have been a matter of routine optimization within the teachings of Yamada et al to determine a suitable distance between the upper surfaces of the conductive layer and the substrate, to achieve the substrate 1 and conductive layer 9a formation steps of Yamada et al to be performed.

Notwithstanding, it would have been an obvious matter of design choice bounded by well known manufacturing constraints and ascertainable by routine experimentation and optimization to choose these particular dimensions because applicant has not disclosed that the dimensions are for a particular unobvious purpose, produce an unexpected result, or are otherwise critical, and it appears prima facie that the process would possess utility using another dimension. Indeed, it has been held that mere dimensional limitations are prima facie obvious absent a disclosure that the limitations are for a particular unobvious purpose, produce an unexpected result, or are otherwise critical. See, for example, In re Rose, 220 F.2d 459, 105 USPQ 237 (CCPA 1955); In re Rinehart, 531 F.2d 1048, 189 USPQ 143 (CCPA 1976); Gardner v. TEC Systems, Inc., 725 F.2d 1338, 220 USPQ 777 (Fed. Cir. 1984), cert. denied, 469 U.S. 830, 225 USPQ 232 (1984); In re Dailey, 357 F.2d 669, 149 USPQ 47 (CCPA 1966).

Claims 14 and 15 would be allowable if rewritten to overcome the objection(s) set forth in this Office action and to include all of the limitations of the base claim and any intervening claims.

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Claims 3, 4, 7-11, 22, and 23, are allowed.

Any inquiry of a general nature or relating to the status of this application should be directed to the Group Receptionist whose telephone number is (703) 308-0956 until 2/4/04. See MPEP 203.08.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to examiner Joannie Adelle García whose telephone number is (571) 272-1861. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri, can be reached on (571) 272-1855. The fax number for this group is 703-872-9306 for before final submissions, 703-872-9306 for after final submissions and the customer service number for group 2800 is (703) 872-9317. Updates can be found at http://www.uspto.gov/web/info/2800.htm.

George Fourson Primary Examiner Art Unit 2823

JAG September 14, 2004

George Fourson Primary Examiner